

TRIAC(Through Hole/Isolated)

TMG2CQ60F

(T_j=150°C)

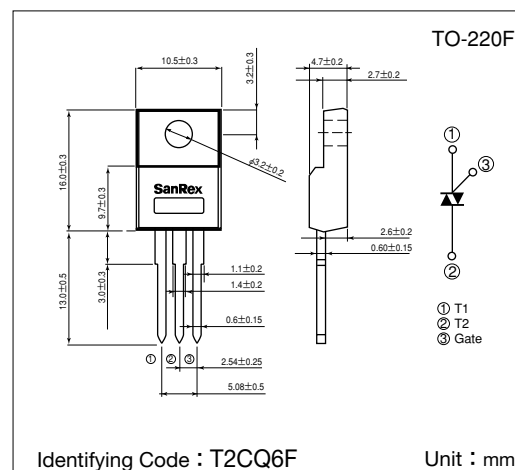
SanRex Triac TMG2CQ60F is designed for full wave AC control applications. It can be used as an ON/OFF function or for phase control operation.

Typical Applications

- Home Appliances : Washing Machines, Vacuum Cleaners, Rice Cookers, Micro Wave Ovens, Hair Dryers, other control applications
- Industrial Use : SMPS, Copier Machines, Motor Controls, Dimmer, SSR, Heater Controls, Vending Machines, other control applications

Features

- I_{T(RMS)}=2A
- High Surge Current
- Lead-Free Package



Identifying Code : T2CQ6F

Unit : mm

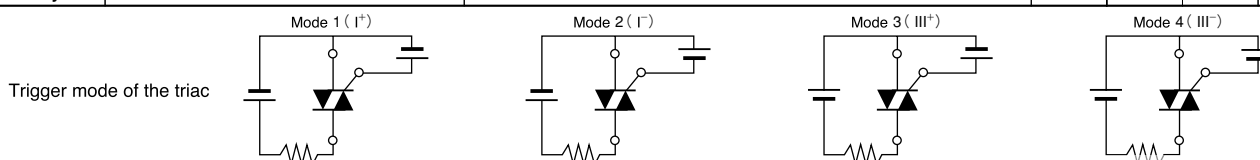
Maximum Ratings

(T_j=25°C unless otherwise specified)

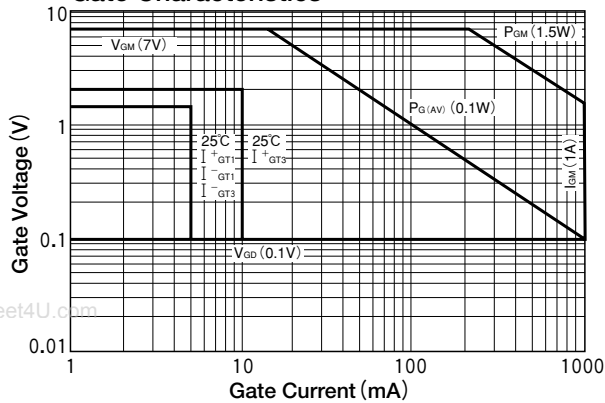
Symbol	Item	Reference	Ratings	Unit
V _{DRM}	Repetitive Peak Off-State Voltage		600	V
I _{T(RMS)}	R.M.S. On-State Current	T _c =129°C	2	A
I _{TSM}	Surge On-State Current	One cycle, 50Hz/60Hz, Peak value non-repetitive	18/20	A
I ² t	I ² t (for fusing)		1.67	A ² S
P _{GM}	Peak Gate Power Dissipation		1.5	W
P _{G(AV)}	Average Gate Power Dissipation		0.1	W
I _{GM}	Peak Gate Current		1	A
V _{GM}	Peak Gate Voltage		7	V
V _{ISO}	Isolation Breakdown Voltage (R.M.S)	A.C.1minute	1500	V
T _j	Operating Junction Temperature		-40~+150	°C
T _{stg}	Storage Temperature		-40~+150	°C
	Mass		2	g

Electrical Characteristics

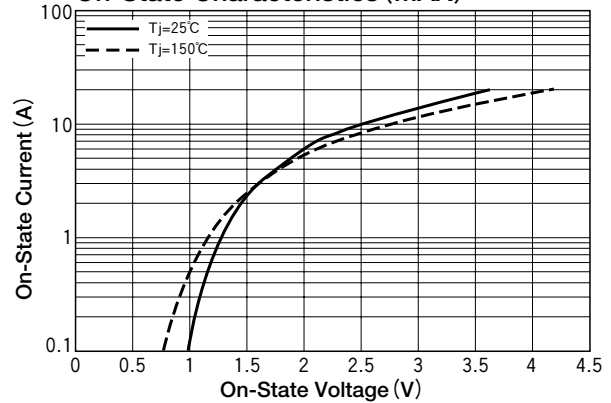
Symbol	Item		Reference	Ratings			Unit
				Min.	Typ.	Max.	
I _{DRM}	Repetitive Peak Off-State Current		V _D =V _{DRM} , Single phase, half wave, T _j =150°C			1	mA
V _{TM}	Peak On-State Voltage		I _T =3A, Inst. measurement			1.6	V
I _{GT1} ⁺	1	Gate Trigger Current	V _D =6V, R _L =10Ω			15	mA
I _{GT1} [−]	2					15	
I _{GT3} ⁺	3					—	
I _{GT3} [−]	4					15	
V _{GT1} ⁺	1	Gate Trigger Voltage				1.5	V
V _{GT1} [−]	2					1.5	
V _{GT3} ⁺	3					—	
V _{GT3} [−]	4					1.5	
V _{GD}	Non-Trigger Gate Voltage		T _j =150°C, V _D = $\frac{1}{2}$ V _{DRM}	0.1			V
(dv/dt) _c	Critical Rate of Rise of Off-State Voltage at Commutation		T _j =150°C, (di/dt) _c =−1A/ms, V _D = $\frac{2}{3}$ V _{DRM}	1			V/μs
I _H	Holding Current				2		mA
R _{th(j-c)}	Thermal Resistance		Junction to case			7.5	°C/W
R _{th(j-a)}			Junction to ambient			50	°C/W



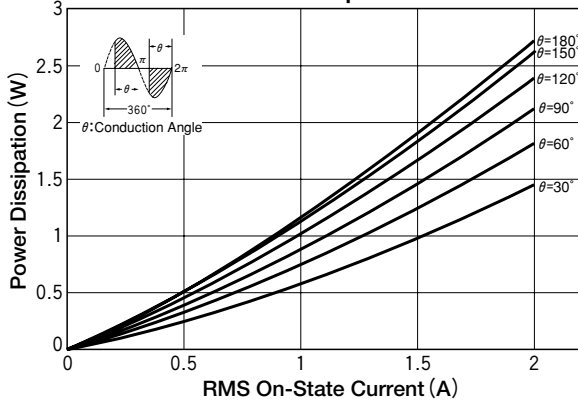
Gate Characteristics



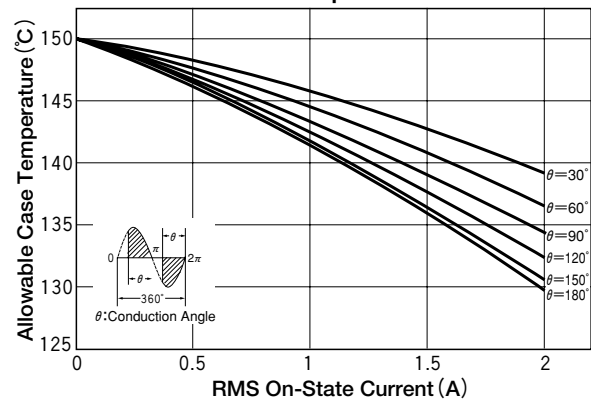
On-State Characteristics (MAX)



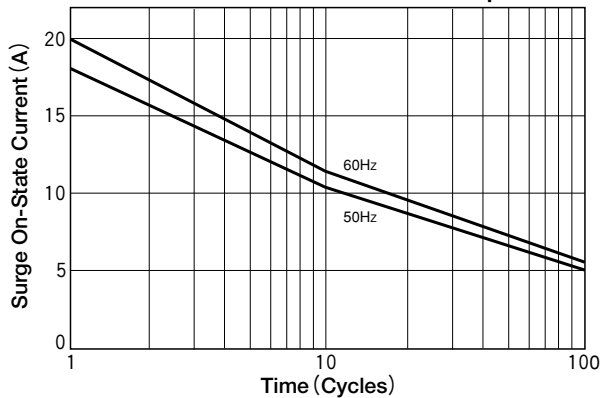
RMS On-State Current vs Maximum Power Dissipation



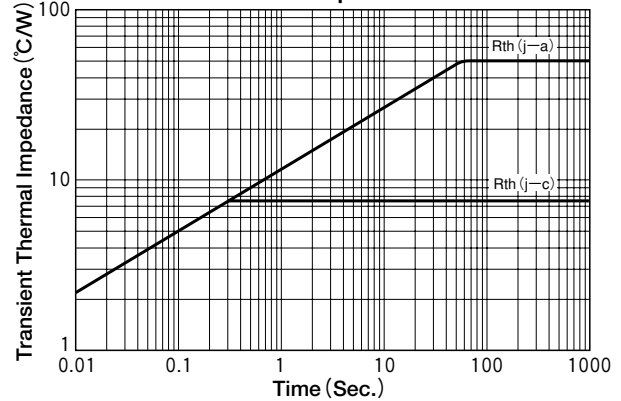
RMS On-State vs Allowable Case Temperature



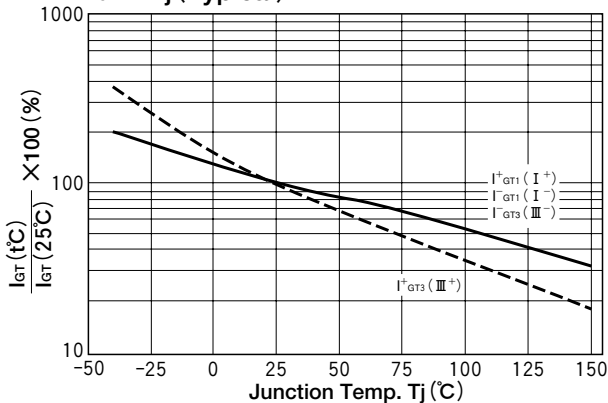
Surge On-State Current Rating (Non-Repetitive)



Transient Thermal Impedance



$I_{GT} - T_j$ (Typical)



$V_{GT} - T_j$ (Typical)

